



FEATURES

- HIGH RELIABILTY PLASTIC HYBRID MODULE
- SUITABLE FOR MATRIX CONVERTER APPLICATIONS
- POSITIVE TEMPERATURE COEFFICIENT OF V_{CEsat}
- VERY LOW Cies, Coes, Cres

Maximum Rated Values (At 25°C unless otherwise stated)

Symbol	Name	Conditions	Value	Unit
V _{CES}	Collector Emitter Voltage		1200	V
V _{GES}	Gate Emitter Voltage		±20	V
l.	DC-Collector Current	T _C = 25°C	200	А
I _C		T _C = 65°C	100	А
I _{CM}	Repetitive Peak Collector Current	$T_C = 25^{\circ}C;$ $t_P = 1 \text{ms}$	300	А
P _{TOT}	Power Dissipation	Per IGBT, T _{CASE} = 25°C	1300	W
T _J	Operating Temperature		-55+125	∞
T _{ST}	Storage Temperature		-55+150	∞

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Symbol	Name	Conditions		typ.	max.	Unit
$V_{(BR)CES}$	Collector Emitter Breakdown Voltage	$V_{GE} = 0V$, $I_C = 4mA$	1200	-	-	٧
$J_{GE(th)}$	Gate Threshold Voltage		5.0	5.8	6.5	٧
CES	Collector-Emitter Cut-Off Current		-	-	5000	μA
GES	Gate-Emitter Leakage Current		-	-	400	nA
J _{CE(sat)}	Collector-Emitter Saturation Voltage	V _{GE} = 15V, I _C = 150A	-	1.75	2.15	V
Cies	Input Capacitance	V _{GE} = 0V	-	10.5	-	μF
O _{res}	Reverse Transfer Capacitance	V _{CE} = 25V	-	0.4	-	nF
-CE	Stray Inductance (module)	$f = 1MHz$, $T_J = 125$ °C	-	15	-	nH
T _{d(on)}	Turn On Delay Time	V _{CC} = 600V	-	0.26	-	μs
Γ _r	Rise Time	V _{GE} = ±15V	-	0.03	-	μs
$\Gamma_{d(off)}$	Turn Off Delay Time	I _C = 300A ind. load	-	0.42	-	μs
Γ _f	Fall Time	$R_{G(on)} = R_{G(off)} = 3.3\Omega$	-	0.07	-	μs
-on	Turn On Energy Loss	T _J = 125℃	-	16	-	mJ
= off	Turn Off Energy Loss		-	14.5	-	mJ

Inverse Diode Characteristic Values

Symbol	Name	Conditions			min.	typ.	max.	Unit
V_{F}	Forward Voltage	$I_F = 150A$,	$V_{\text{GE}}=0V, \\$	$T_J = 25^{\circ}\!\text{C}$	-	1.65	2.5	V
	Torward Voltage	I _F =150A,	$V_{\text{GE}}=0V, \\$	T _J = 125℃	-	1.65	-	
I _{RRM}	Peak Reverse Recovery Current	I _F = 150A,		T _J = 125℃	-	210	-	Α
Q _{rr}	Reverse Recovery Charge	I _F = 150A,		T _J = 125℃	-	30	-	μC
E _{REC}	Reverse Recovery Energy	I _F = 150A,		T _J = 125℃	-	13.0	-	mJ

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Symbol	Name	Conditions	min.	typ.	max.	Unit
R_{thJC}	Thermal Resistance Junction to Case	per IGBT per Diode	-	0.10 0.17	-	°CW⁻¹ °CW⁻¹
R _{thCK}	Thermal Resistance Case to Heatsink	per module ¹	-	-	0.01	°CW⁻¹
М	Mounting Torque	module mounting screw terminals	TBA TBA	-	TBA TBA	Nm Nm
W	Module Weight		-	TBA	-	g

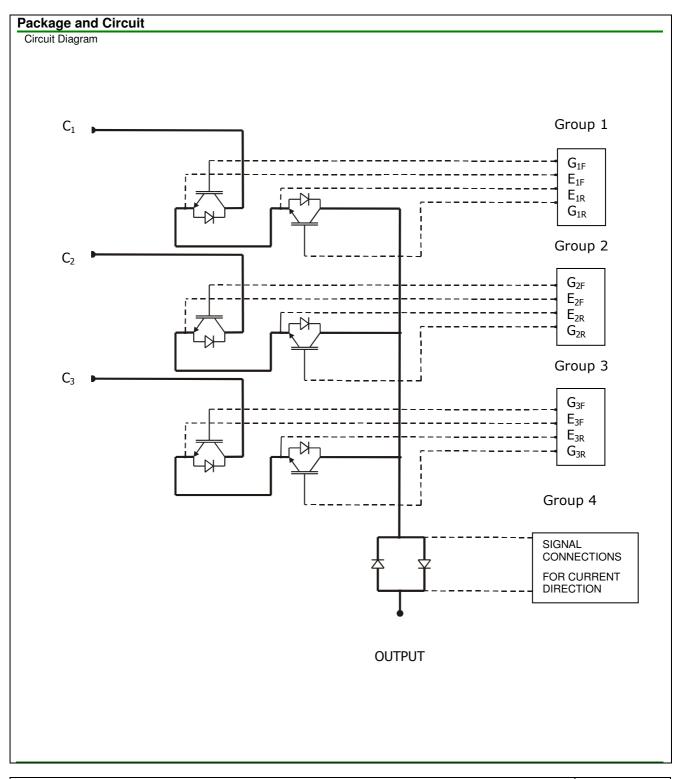
¹ thermal grease, planar heat-sink

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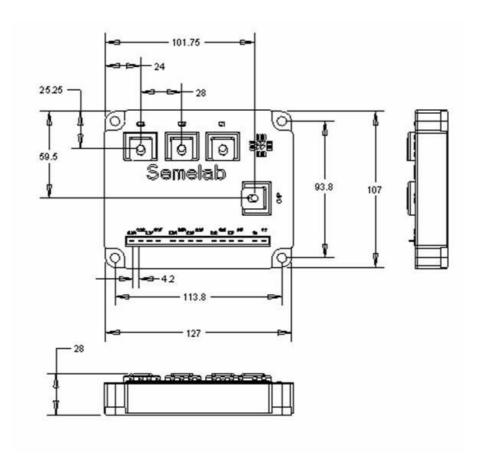


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Package Outline

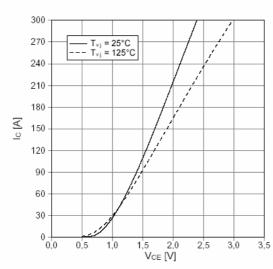


Dimensions in mm

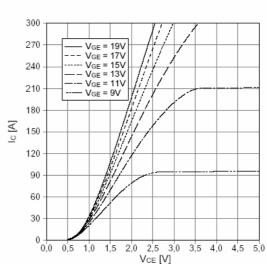
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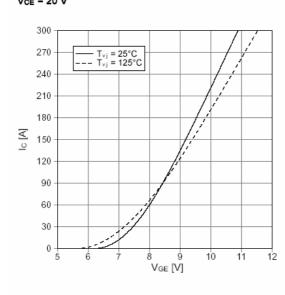




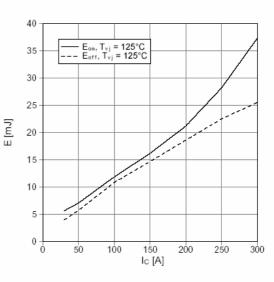
output characteristic IGBT-inverter (typical) Ic = f (VcE) T_{vj} = 125°C



transfer characteristic IGBT-inverter (typical) $I_C = f$ (VGE) $V_{CE} = 20$ V



switching losses IGBT-inverter (typical) $E_{on} = f(I_C)$, $E_{off} = f(I_C)$ $V_{GE} = \pm 15$ V, $R_{Gon} = 2.4$ Ω , $R_{Goff} = 2.4$ Ω , $V_{CE} = 600$ V

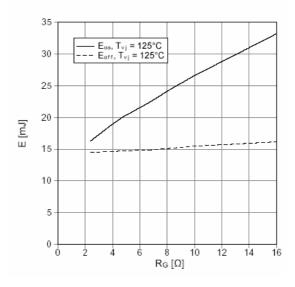


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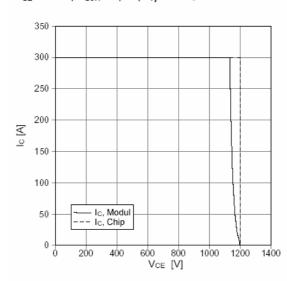
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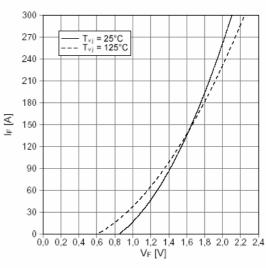
switching losses IGBT-Inverter (typical) $E_{on} = f$ (R_G), $E_{off} = f$ (R_G) $V_{GE} = \pm 15$ V, $I_{C} = 150$ A, $V_{CE} = 600$ V



reverse bias safe operating area IGBT-inv. (RBSOA) I_C = f (VcE) V_{GE} = ±15 V, R_{Goff} = 2,4 Ω , T_{vj} = 125°C

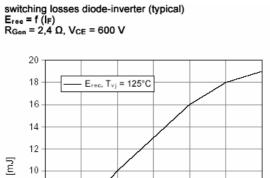


forward characteristic of diode-inverter (typical) $I_F = f(V_F)$

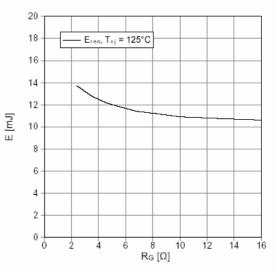


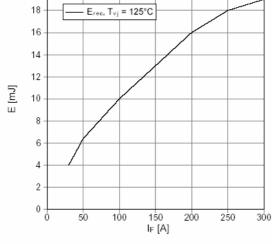
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switching losses diode-inverter (typical) $E_{reo} = f(R_G)$ $I_F = 150 \text{ A, V}_{CE} = 600 \text{ V}$





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